National Semiconductor

November 1994

54F/74F243
Quad Bus Transceiver with TRI-STATE® Outputs

General Description

The ’F243 is a quad bus transmitter/receiver designed for 4-line asynchronous 2-way data communications between data busses.

Features

- 2-Way asynchronous data bus communication
- Input clamp diodes limit high-speed termination effects
- Guaranteed 4000V minimum ESD protection

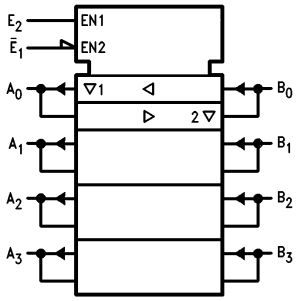
Commercial	Military	Package Number	Package Description
	54F243DM (Note 2)	J14A	14-Lead Ceramic Dual-In-Line
74F243SC (Note 1)		M14A	14-Lead (0.150″ Wide) Molded Small Outline, JEDEC
	54F243FM (Note 2)	W14B	14-Lead Cerpack
	54F243LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13″ reel. Use Suffix = SCX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbol

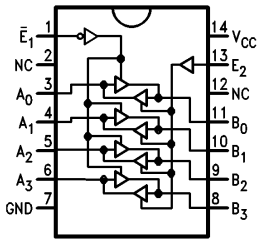
IEEE/IEC



TL/F/9502–3

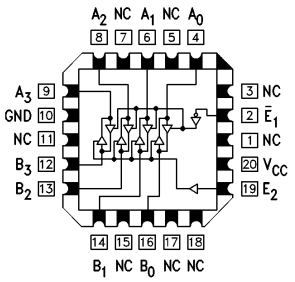
Connection Diagrams

Pin Assignment for DIP, SOIC and Flatpak



TL/F/9502–1

Pin Assignment for LCC



TL/F/9502–2

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

©1995 National Semiconductor Corporation

RRD-B30M105/Printed in U. S. A.

Unit Loading/Fan Out

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{E}_1$	Enable Input (Active LOW)	1.0/1.67	20 μA/−1 mA
E_2	Enable Input (Active HIGH)	1.0/1.67	20 μA/−1 mA
A_n, B_n	Inputs	3.5/2.67	70 μA/−1.6 mA
	Outputs	600/106.6(80)	−12 mA/64 mA(48 mA)

Truth Table

Inputs		Inputs/Outputs	
$\overline{E}_1$	E_2	A_n	B_n
L	L	Input	B = A
L	H	N/A	N/A
H	L	Z	Z
H	H	A = B	Input

H = HIGH Voltage Level
L = LOW Voltage Level
Z = High Impedance
N/A = Not Allowed

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)
ESD Last Passing Voltage (Min)	4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F Min	54F/74F Typ	54F/74F Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54F 10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA (A_n, B_n)
		54F 10% V_{CC}	2.0					I_{OH} = −12 mA (A_n, B_n)
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA (A_n, B_n)
		74F 10% V_{CC}	2.0					I_{OH} = −15 mA (A_n, B_n)
		74F 5% V_{CC}	2.7					I_{OH} = −3 mA (A_n, B_n)
V_{OL}	Output LOW Voltage	54F 10% V_{CC}			0.55	V	Min	I_{OL} = 48 mA (A_n, B_n)
		74F 10% V_{CC}			0.55			I_{OL} = 64 mA (A_n, B_n)
I_{IH}	Input HIGH Current	54F			20.0	μA	Max	V_{IN} = 2.7V
		74F			5.0			
I_{BVI}	Input HIGH Current Breakdown Test	54F			100	μA	Max	V_{IN} = 7.0V ($\overline{E}_1$, E_2)
		74F			7.0			
I_{BVIT}	Input HIGH Current Breakdown (I/O)	54F			1.0	mA	Max	V_{IN} = 5.5V (A_n, B_n)
		74F			0.5			
I_{CEX}	Output HIGH Leakage Current	54F			250	μA	Max	V_{OUT} = V_{CC}
		74F			50			
V_{ID}	Input Leakage Test	74F	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.0	mA	Max	V_{IN} = 0.5V ($\overline{E}_1$, E_2)
I_{IH} + I_{OZH}	Output Leakage Current				70	μA	Max	V_{OUT} = 2.7V (A_n, B_n)
I_{IL} + I_{OZL}	Output Leakage Current				−1.6	mA	Max	V_{OUT} = 0.5V (A_n, B_n)
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V (A_n, B_n)
I_{CCH}	Power Supply Current			64	80	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			64	90	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			71	90	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

Symbol	Parameter	74F			54F		74F		Units
		$T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			T_A, V_{CC} = Mil, $C_L = 50$ pF		T_A, V_{CC} = Com, $C_L = 50$ pF		
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH}	Propagation Delay	2.5	4.0	5.2	2.0	6.5	2.0	6.2	ns
t_{PHL}	A_n to B_n, B_n to A_n	2.5	4.0	5.2	2.0	8.5	2.0	6.5	
t_{PZH}	Output Enable Time	2.0	4.3	5.7	2.0	8.0	2.0	6.7	ns
t_{PZL}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	5.8	7.5	2.0	10.5	2.0	8.5	
t_{PHZ}	Output Disable Time	2.0	4.5	6.0	1.5	7.5	1.5	7.0	
t_{PLZ}	$\overline{E}_1$ to B_n, E_2 to A_n	2.0	4.5	6.0	2.0	8.5	2.0	7.0	

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

74F 243 S C X

Temperature Range Family
- 74F = Commercial
- 54F = Military

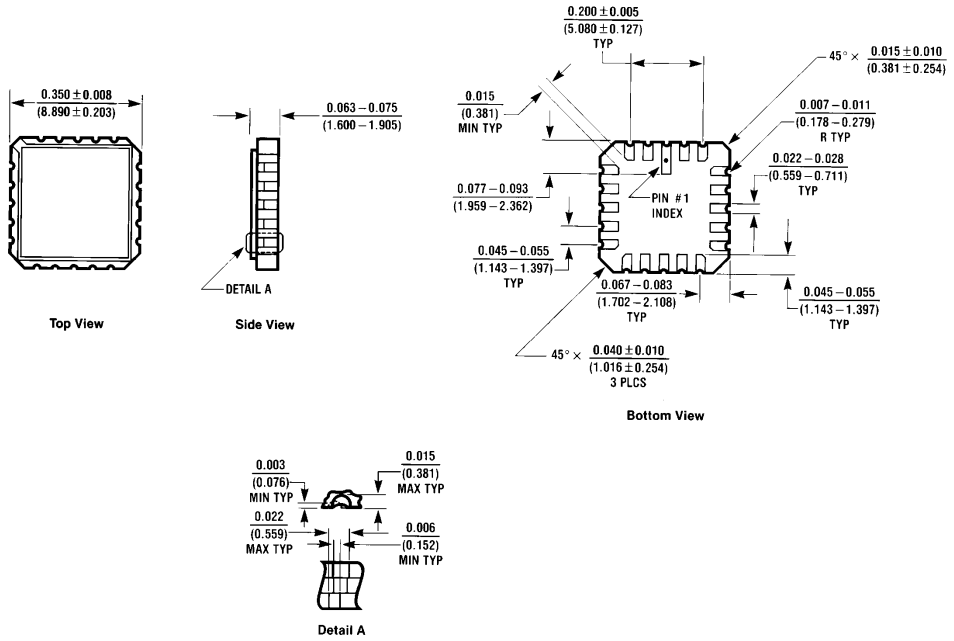
Device Type

Package Code
- D = Ceramic DIP
- F = Flatpak
- L = Leadless Chip Carrier (LCC)
- S = Small Outline SOIC JEDEC

Temperature Range
- C = Commercial (0°C to +70°C)
- M = Military (−55°C to +125°C)

Special Variations
- QB = Military grade device with environmental and burn-in processing
- X = Devices shipped in 13″ reel

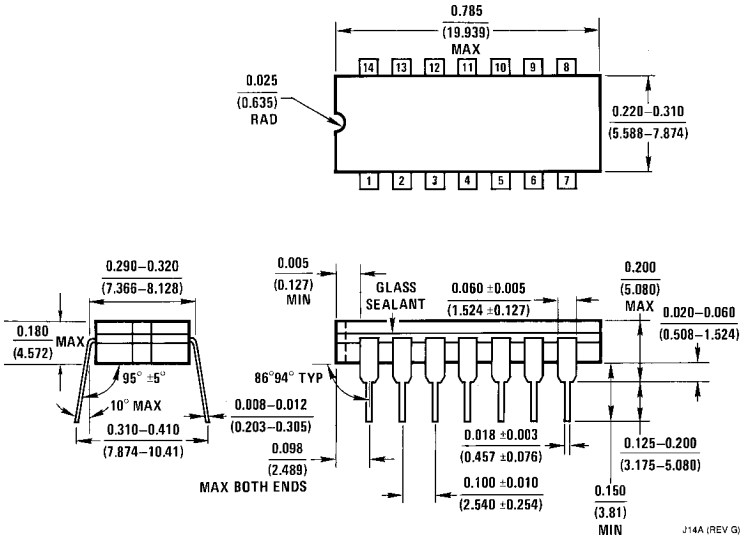
Physical Dimensions inches (millimeters)



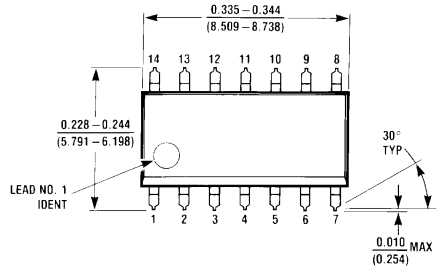
E20A (REV D)

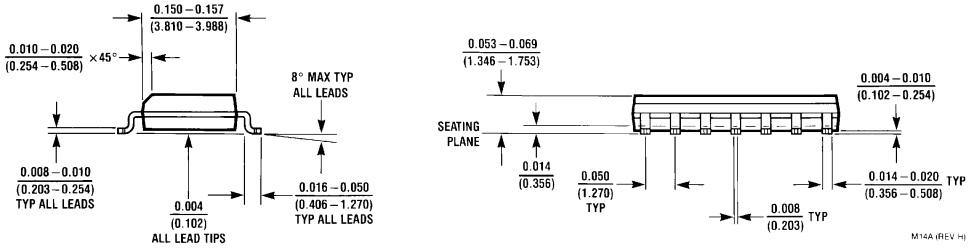
20-Lead Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

Physical Dimensions inches (millimeters) (Continued)



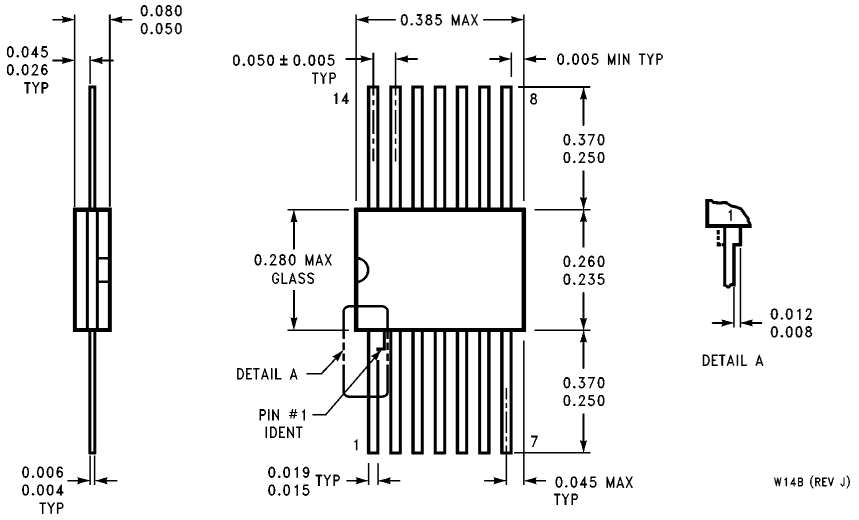
14-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J14A





14-Lead (0.150″ Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Ceramic Flatpak (F)
NS Package Number W14B

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

National Semiconductor Europe
Fax: (+49) 0-180-530 85 86
Email: cnjwge@tevm2.nsc.com
Deutsch Tel: (+49) 0-180-530 85 85
English Tel: (+49) 0-180-532 78 32
Français Tel: (+49) 0-180-532 93 58
Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.

Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9